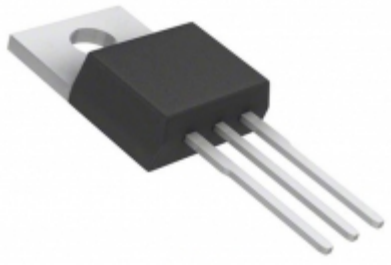

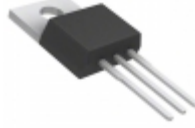






	<h2 style="color: red;">FQP34N20</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQP34N20</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 200V 31A TO-220</p> <p><b>Datenblätter:</b> <a href="#">1.FQP34N20.pdf</a> <a href="#">2.FQP34N20.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 34437 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQP34N20</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 200V 31A TO-220
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	34437 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	31A (Tc)
Rds On (Max) @ Id, Vgs	75 mOhm @ 15.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	78nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3100pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube

FQP34N20 ist neu im Original, Suche FQP34N20 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP34N20 Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQP34N20: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQP33N10</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 33A TO-220	 <b>FQP33N10L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 33A TO-220	 <b>FQP34N20</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 31A TO-220	 <b>FQP34N20L</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 31A TO-220
 <b>FQP33N10</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 33A TO-220	 <b>FQP32N20C_F080</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 28A TO-220	 <b>FQP3N25</b> Fairchild/ON Semiconductor MOSFET N-CH 250V 2.8A TO-220	 <b>FQP3N25</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 2.8A TO-220

### heiße Teile

Mehr

⊗ FQP24N08	↔ FQP24N40	⇒ FQP27N25	D FQP27N25	⇒ FQP27N60
⊣ FQP27P06	⊗ FQP27P06	D FQP2N60B	⇒ FQP2N60C	⇒ FQP2N60C
⊗ FQP2N65C	⊣ FQP30N06	⊗ FQP30N06	↔ FQP30N06L	⇒ FQP30N06L
D FQP32N12V2	⊗ FQP32N12V2	⊣ FQP32N20	⊗ FQP32N20C	⇒ FQP32N20C
⇒ FQP33N10	↔ FQP33N10	⊗ FQP33N10L	⊣ FQP33N10L	⇒ FQP34N20
↔ FQP34N20L	⇒ FQP34N20L	D FQP3N50C	⊗ FQP3N60C	⊣ FQP3N60C
⊗ FQP3N80C	D FQP3N80C	⇒ FQP44N08	↔ FQP44N08	⇒ FQP44N10
⊣ FQP44N10	⊗ FQP44N10F	↔ FQP44N10F	⇒ FQP45N03L	⇒ FQP45N03LM
⊗ FQP45N15V2	⊣ FQP45N15V2	⊗ FQP45N20A	D FQP46N15	⇒ FQP46N15
↔ FQP47N06	⊗ FQP47P06	⊣ FQP47P06	⊗ FQP47P06L	⇒ FQP47P06_

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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